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# Raman scattering studies of the GeS<sub>2</sub>–Ga<sub>2</sub>S<sub>3</sub>–CsCl glassy system

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#### **Abstract**

Room temperature Raman spectra of samples on four serials within  $GeS_2$ – $Ga_2S_3$ –CsCl glassy system have been investigated systematically. Based on the analysis of the local coordination surroundings of  $Cs^+$  ions, the similarities and changes of Raman spectra for glass  $Ga_2S_3$ –2CsCl and bridged molecular  $GaCl_3$  were explained successfully. With a profound consideration of the effect of  $Cs^+$  ions on mixed anion units  $(GaS_{4-x}Cl_x)$  and bridged units  $(Ga_2S_{6-x}Cl_x)$  and the corresponding micro-structural model, the Raman spectral evolution of the samples within  $GeS_2$ – $Ga_2S_3$ –CsCl glassy system was reasonably elucidated. © 2004 Elsevier Ltd. All rights reserved.

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#### 1. Introduction

 $Ga_2S_3$ -based chalcohalide glasses have been considered as promising hosts for rare-earth (RE) doped active devices [1–3]. In addition, due to their higher optical non-linear coefficient and smaller two-phonon absorption, recently the  $Ga_2S_3$ -based chalcohalide glasses have become a hot-point of research and development particularly for applications such as ultra-fast all optical switching [4]. Because the above-mentioned two properties all have an intimate relationship with the microstructure of  $Ga_2S_3$ -based chalcohalide glasses, therefore, an understanding and utilization of the micro-structural research findings have practical importance.

Much research on the binary Ge–S and ternary Ge–Ga–S glasses has been done [5–7]. However, the micro-structural research about the GeS<sub>2</sub>–Ga<sub>2</sub>S<sub>3</sub>–CsCl glassy system is scarce. Based on the similarity of Raman spectra between

the CsGaS<sub>1.5</sub>Cl glass and GaCl<sub>3</sub> molecule, Tverjanovich et al. [8] proposed that the CsGaS<sub>1.5</sub>Cl glass is a one-dimensional chain structure formed by the double edge-sharing tetrahedral (ClS<sub>1/2</sub>GaS<sub>2</sub>GaS<sub>1/2</sub>Cl)<sup>2-</sup>, but the differences between the two Raman spectra were not ascribed. Furthermore, in Ref. [9], they also reported the Raman spectra of samples on the compositional line CsGaS<sub>1.5</sub>Cl-0.15Ga<sub>2</sub>S<sub>3</sub>0.85GeS<sub>2</sub> within GeS<sub>2</sub>-Ga<sub>2</sub>S<sub>3</sub>-CsCl glasses. However, the evolution of microstructural units (m.u.) with compositional change was not further studied. Through further considering the local coordination of Cs<sup>+</sup> ions, Raman spectra of GeS<sub>2</sub>-Ga<sub>2</sub>S<sub>3</sub>-CsCl glasses were further discussed in this work.

## 2. Sample preparation and measurements

The samples were prepared by conventional meltquenching techniques. Details of the preparations were similar to the procedure in our previous paper [10]. GeS<sub>2</sub>– Ga<sub>2</sub>S<sub>3</sub>–CsCl glassy samples on four composition serials

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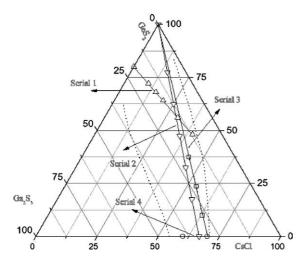


Fig. 1. GeS<sub>2</sub>–Ga<sub>2</sub>S<sub>3</sub>–CsCl pseudo-ternary phase diagram [11] showing the glass-forming region and glass molar compositions investigated in this study. Serial 1:  $(0.8\text{GeS}_2-0.2\text{Ga}_2\text{S}_3)_{1-x}(\text{CsCl})_x$  (x=0, 0.1, 0.15, 0.2, 0.3, 0.4). Serial 2:  $(\text{GeS}_2)_{1-1.5x}$ – $(\text{Ga}_2\text{S}_3)_{0.5x}$ – $(\text{CsCl})_x$  (x=0.15, 0.25, 0.35, 0.45, 0.55, 0.6, 0.64, 0.667). Serial 3:  $(\text{GeS}_2)_{1-10x/7}$ – $(\text{Ga}_2\text{S}_3)_{3x/7}$ – $(\text{CsCl})_x$  (x=0.4, 0.537, 0.563, 0.7). Serial 4:  $(\text{Ga}_2\text{S}_3)_{1-x}$ – $(\text{CsCl})_x$  (x=0.6, 0.667, 0.7).

were probed (Fig. 1). In addition, several samples (0.5GeS<sub>2</sub>(orGeS)–0.5CsCl) were prepared according to the similar preparation process of GeS<sub>2</sub>–Ga<sub>2</sub>S<sub>3</sub>–CsCl glasses.

The chemical compositions of the samples were analyzed using an energy-dispersive XRF analyzer. Homogeneity and amorphous characteristics of the prepared materials were confirmed by optical and electron microscopy and X-ray diffraction with  $\text{Cu K}_{\alpha}$  radiation. Because of the poor water-resistance of samples with high CsCl content, the Raman measurement was conducted by focusing the laser into the sample within the silica ampoule in a back (180°) scattering configuration by the micro Raman Spectrometer (Type: Renishaw RM-1000) using the 632.8 nm laser line.

# 3. Experimental results and discussion

The amorphous GeS<sub>2</sub>–Ga<sub>2</sub>S<sub>3</sub>–CsCl samples were optically homogeneous to the eye and according to the methods given above. The glassy compositions were determined with X-ray fluorescence spectroscopy. The analytical compositions of the GeS<sub>2</sub>–Ga<sub>2</sub>S<sub>3</sub>–CsCl glasses on serial 1 are reported in Table 1. The results of the XRF analysis revealed that the difference in composition between a batch and the glass sample was within reasonable range. So, for the sake of clarity, the glasses will be labeled by their batch composition in the following text.

#### 3.1. Ga<sub>2</sub>S<sub>3</sub>-CsCl pseudo-binary system

It is well known that (GaS<sub>4</sub>) and (GaCl<sub>4</sub>) tetrahedra have an edge-sharing tendency and mixed tetrahedra (GaS<sub>r</sub>Cl<sub>4-r</sub>) can be formed easily [7,12,13]. In addition, Ramos etc. [14] pointed out that Cs<sup>+</sup> exists as the form of (CsCl<sub>n</sub>) clusters within Ga-La-S-CsCl glasses. Last, based on the m.u. within the CsGa<sub>1.5</sub>SCl glass proposed in Ref. [8,9], it is reasonable to suppose that within Ga<sub>2</sub>S<sub>3</sub>-CsCl glasses,  $(GaS_xCl_{4-x})$  clusters can be easily formed; these clusters can easily form edge-sharing dimmer when two of them border; these dimmers can be connected into chains through two coordinated sulfur atoms; and Cs+ ions are homogeneously dispersed in the glassy network as the Cl atoms for their nearest neighbor. So the addition of Cs<sup>+</sup> mainly influences on the Ga-Cl bonds while less on Ga-S ones, especially, on the inner bridge sulfur bonds within (Ga<sub>2</sub>S<sub>2</sub>S<sub>2/2</sub>Cl<sub>2</sub>) m.u. Based on these deductions, later it will be verified that the Raman spectra evolution of Ga<sub>2</sub>S<sub>3</sub>-2CsCl glass and GaCl<sub>3</sub> can be successfully elucidated.

The strongest Raman peak of  $GaCl_3$  is located at  $413 \text{ cm}^{-1}$  (Fig. 2), assigned to the  $\nu_1$  mode (Fig. 3) of the dimmer  $Ga_2Cl_6$  [13]. But when it comes to the  $Ga_2S_3$ –2CsCl glass, this band shifts to  $400 \text{ cm}^{-1}$  and its intensity is not the strongest one. Considering the similarity of S and Cl, the structural difference between the  $Ga_2S_3$ –2CsCl glass and

Table 1 Batch and analytical compositions of  $GeS_2$ – $Ga_2S_3$ –CsCl glasses on serial 1

	Batch (mol%)	Ge (at.%)	Ga (at.%)	S (at.%)	Cs (at.%)	Cl (at.%)
1	80GeS <sub>2</sub> - 20Ga <sub>2</sub> S <sub>3</sub>	28 (26.7)	9 (8)	63 (65.3)		
2	72GeS <sub>2</sub> – 18Ga <sub>2</sub> S <sub>3</sub> – 10CsCl	24 (24)	8 (7.2)	58 (58.8)	5 (5)	5 (5)
3	64GeS <sub>2</sub> – 16Ga <sub>2</sub> S <sub>3</sub> – 20CsCl	23 (21.3)	6 (6.4)	52 (52.3)	10 (10)	9 (10)
4	56GeS <sub>2</sub> – 14Ga <sub>2</sub> S <sub>3</sub> – 30CsCl	19 (18.7)	7 (5.6)	45 (45.7)	15 (15)	14 (15)

The values in brackets are calculated from the batch compositions. The error of compositional analysis is within  $\pm 1\%$ .

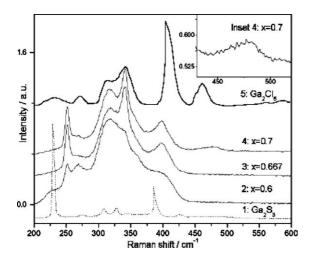


Fig. 2. Room temperature Raman spectra of samples within (1-x) Ga<sub>2</sub>S<sub>3</sub>–xCsCl system and GaCl<sub>3</sub> molecule.

Ga<sub>2</sub>Cl<sub>6</sub> originates mainly from the Cs<sup>+</sup> ions. Compared to Cs–Cl bonds, the Ga–Cl bonds are more covalent, so the addition of Cs<sup>+</sup> certainly makes the Ga–Cl bonds harden and weaken and displaces the chloric atoms towards the Cs<sup>+</sup> ions. In addition, according to the theory of molecular vibration [15], the oscillating frequency bears a relationship shown as follows

$$\nu \propto \sqrt{\frac{f}{\mu}}$$
 (1)

where f is a constant related to bond strength, and  $\mu$  is the discount mass. So it is due to the presence of Cs<sup>+</sup> that the  $\nu_1$  mode of (Ga<sub>2</sub>S<sub>2</sub>S<sub>2/2</sub>Cl<sub>2</sub>) units shifts 13 cm<sup>-1</sup> toward a lower wavenumber compared to the corresponding mode of the (Ga<sub>2</sub>Cl<sub>6</sub>) unit. Finally, due to the decreasing coupling which originates from the small difference between Ga–Cl and Ga–S bonds, the  $\nu_1$  mode of (Ga<sub>2</sub>S<sub>2</sub>S<sub>2/2</sub>Cl<sub>2</sub>) units comes forth as a broad band between 370 and 430 cm<sup>-1</sup>.

Furthermore, the variances of several other Raman modes between Ga<sub>2</sub>S<sub>3</sub>–2CsCl glass and GaCl<sub>3</sub> also verified

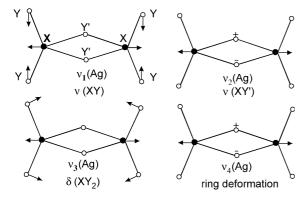


Fig. 3. Several normal coordination models of  $X_2Y_6$  units.

the validity of the proposed model. First, nearly no change happens about the  $v_2$  mode located at about 318 cm<sup>-1</sup> that is related to the vibrating of inner bridge bonds. Secondly, according to Ref. [8], the  $\nu_4$  mode of (Ga<sub>2</sub>Cl<sub>6</sub>) sited at about 167 cm<sup>-1</sup> has a relationship with the vibration of inner bridge chlorines. On the spectra of Ga<sub>2</sub>S<sub>3</sub>-2CsCl glass, the corresponding mode has small shift (located at about 165 cm<sup>-1</sup>). Thirdly, the  $\nu_3$  mode of Ga<sub>2</sub>Cl<sub>6</sub> locates at about 100 cm<sup>-1</sup> that is ring in-plane bend vibrating [8]. While for the Ga<sub>2</sub>S<sub>3</sub>-2CsCl glass, the corresponding mode shifts 14 cm<sup>-1</sup> and locates at about 86 cm<sup>-1</sup>. Fourthly, the peak at about 268 cm<sup>-1</sup> which is  $v_3^{(Ag)} + v_4^{(Ag)}$  on the Raman spectra of GaCl<sub>3</sub> shifts about 18 cm<sup>-1</sup> when it comes to the glass Ga<sub>2</sub>S<sub>3</sub>-2CsCl. Finally, about the peak at about  $340 \,\mathrm{cm}^{-1}$  that is  $v_3^*2$ , no shift happens on the Raman spectra of the Ga<sub>2</sub>S<sub>3</sub>-2CsCl glass and GaCl<sub>3</sub>.

Finally, the Raman spectra evolution of samples 2-4 further verified the correctness of the proposed model. On the Raman spectrum of sample 2, the broadband at about 233 cm<sup>-1</sup> is ascribed to the characteristic Raman peak of the crystal Ga<sub>2</sub>S<sub>3</sub> m.u. (Fig. 2(1)). It indicates that crystal Ga<sub>2</sub>S<sub>3</sub> m.u. still exist when less CsCl is added. Moreover, the little peak at about 269 cm<sup>-1</sup> is ascribed to the antisymmetric stretching vibration of (S<sub>3</sub>Ga-GaS<sub>3</sub>) ethane-like m.u. [5]. The emergence of the distinct prominence at about  $360 \text{ cm}^{-1}$  that is ascribed to the  $v_1$  mode of this ethane-like m.u. further verified the validity of the ascription. Following the addition of CsCl, the above-mentioned three bands decrease in intensity and shrink to nothing after the ratio of CsCl/Ga<sub>2</sub>S<sub>3</sub> is equal to 2. So it can be concluded that with the addition of CsCl, other m.u. gradually substitute the Ga<sub>2</sub>S<sub>3</sub> crystal and (S<sub>3</sub>Ga–GaS<sub>3</sub>) ethane-like m.u.

Being separated by the crystal Ga<sub>2</sub>S<sub>3</sub> and ethane-like m.u., many  $(GaS_{4-r}Cl_r)$  mixed tetrahedra within sample 2 do not form bridged edge-sharing units. Based on the similarity of S and Cl, the strongest  $v_1$  mode of  $GaS_{4-x}Cl_x$ also should locate at about 340 cm<sup>-1</sup> and shift toward a lower wavenumber due to the Cs-Cl bonds. In addition, the vibrational coupling ability of (Ga<sub>2</sub>S<sub>2</sub>S<sub>2/2</sub>Cl<sub>2</sub>) edge-sharing units drops due to the effect of other m.u. So, compared to sample 3, the Raman spectrum of sample 2 manifest itself a broad peak and a little shoulder within the region 300-350 cm<sup>-1</sup>. Within the insert figure, there exist a prominence at about 477 cm $^{-1}$  that can be ascribed to the vibration of  $S_8$ rings and/or multi-sulfur bonds [5] and a shoulder at about 463 cm<sup>-1</sup> that is the feature of the  $\nu_{13}$  mode of (Ga<sub>2</sub>Cl<sub>6</sub>). This can be explained as follows. When the ratio of Ga<sub>2</sub>S<sub>3</sub>/ CsCl is equal to 1:2, the glasses are completely composed of (Ga<sub>2</sub>S<sub>2</sub>S<sub>2/2</sub>Cl<sub>2</sub>) edge-sharing units. Further increasing the content of CsCl, Ga-Cl bonds can further replace the Ga-S ones because of the larger affinity of Ga-Cl atoms. The replaced S first, forms multi-sulfur bonds and finally leads to the forming of S<sub>8</sub> rings. The more Cl atoms within  $(Ga_2S_{6-x}Cl_x)$  units will make the Raman spectra of sample 4 present more Raman characteristics of (Ga<sub>2</sub>Cl<sub>6</sub>) units. Lastly, sample 2 and 3 are colorless and transparent, while

sample 4 is pale yellow in color. Based on these facts, it can be speculated that the color of sample 4 should be ascribed to the reaction of  $Ga_2S_3$  and superfluous CsCl which lead to the coming into being of  $S_8$  rings.

### 3.2. GeS<sub>2</sub>–Ga<sub>2</sub>S<sub>3</sub>–CsCl pseudo-ternary system

To study the interaction of CsCl with germanium and sulfur compounds, the pseudo-binary system GeS<sub>2</sub> (or GeS)–CsCl was probed. Raman spectra (Fig. 4) of two different points in the sample 0.5GeS–0.5CsCl are similar. The strongest peak at 300 cm<sup>-1</sup> is due to the symmetric stretching vibrating of (Ge<sub>4</sub>) tetrahedral [16]. The other broad peaks and shoulders are spectral characteristics of Ge–S glass. No characteristic peaks of crystal GeS appear. That is to say, no GeS crystal m.u. appear even when the batch was conducted according to the GeS compound.

According to the Ref. [8], CsCl can not react with GeS<sub>2</sub> based on the GeS2-CsCl phase diagram. In Fig. 5, the broadband centered at about 780 cm<sup>-1</sup> and the clear shoulder in the region 510-610 cm<sup>-1</sup> are the Raman characteristics of GeO<sub>2</sub> glass [17], originating from oxygen contamination during the preparation procedure. On the Raman spectra of GeS2 glass, the little peak at about 486 cm<sup>-1</sup> is ascribed to the multi-sulfur bonds originating from the compositional fluctuation. Accordingly, the little prominence at about 255 cm<sup>-1</sup> is originated from the (S<sub>3</sub>Ge-GeS<sub>3</sub>) ethane-like m.u. The increased intensity of the peak at about 480 cm<sup>-1</sup> indicates the existence of more S<sub>8</sub> rings in the yellow phase compared to the white phase. First, suppose that the addition of CsCl should have no effect on the (GeS<sub>4</sub>) tetrahedra and no mixed tetrahedra (GeS<sub>4-x</sub>Cl<sub>x</sub>) be formed. Then the S<sub>8</sub> rings in white and yellow phases should be ascribed to the sulfur that dose not react with the Ge. The shoulder centered at about 255 cm<sup>-1</sup> should emerge due to the sulfur stoichiometric deficiency. But no such a distinct prominence appears for the white phase. In addition, the corresponding shoulder shifts to the site at

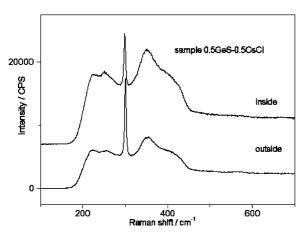


Fig. 4. Raman spectra of sample 0.5GeS-0.5CsCl.

265 cm $^{-1}$  when it comes to the yellow phase. So the addition of CsCl should have a certain effect on the (GeS<sub>4</sub>) and less tetrahedral (GeS<sub>4-x</sub>Cl<sub>x</sub>) be formed. But due to the larger forming probability of (GaS<sub>4-x</sub>Cl<sub>x</sub>) units, it can be inferred that almost no mixed tetrahedra (GeS<sub>4-x</sub>Cl<sub>x</sub>) be formed within GeS<sub>2</sub>–Ga<sub>2</sub>S<sub>3</sub>–CsCl system.

The basic structural unit of GeS<sub>2</sub> glass is (GeS<sub>4</sub>) tetrahedral [6]. The Raman spectrum of GeS<sub>2</sub> glass (Fig. 5) is comparable to those reported previously [6-8]. The strongest peak at 340 cm<sup>-1</sup> is due to the symmetric stretching vibration of (GeS<sub>4</sub>). The shoulder at about 370 cm<sup>-1</sup> is ascribed to the vibration of two edge-sharing (GeS<sub>4</sub>) tetrahedra. The ascription of the band at  $430 \text{ cm}^{-1}$  is still a controversial problem till now [6-8]. The compositional fluctuation leads to the band sited at about 255 cm<sup>-1</sup> originated from the vibrating of (S<sub>3</sub>Ge-GeS<sub>3</sub>) ethane-like m.u. The addition of Ga<sub>2</sub>S<sub>3</sub> into GeS<sub>2</sub> resulted in three distinct changes of the Raman spectra (Fig. 6). First, the low frequency peak gradually shifted from 255 to 270 cm<sup>-1</sup> that is due to the appearance of S<sub>3</sub>Ga–GaS<sub>3</sub> ethane-like units [5]. Secondly, the  $\nu_1$  mode of GeS<sub>2</sub> glass broadens resulting from the similarity of Ge and Ga. Lastly, the appearance of edge-sharing (GaS<sub>4</sub>) tetrahedra leads to the redistribution of intensity in the region 350–440 cm<sup>-1</sup>.

Based on the above analysis, it can be proposed that within  $GeS_2$ – $Ga_2S_3$ –CsCl glasses, only the reaction for  $Ga_2S_3$  and CsCl happens and  $(GaS_{4-x}Cl_x)$  units are formed easily; when two  $(GaS_{4-x}Cl_x)$  units meet the edge-sharing unit  $(Ga_2S_2S_{2/2}Cl_2)$  is formed easily; the  $Cs^+$  ions are also homogeneously dispersed in the glassy network as Cl for its nearest coordination. Later it will be verified that the Raman spectra evolution of  $GeS_2$ – $Ga_2S_3$ –CsCl glasses can be successfully elucidated in terms of these proposals.

Fig. 6 shows the Raman spectra of samples on serial 1. First, the two prominences centered at about 270 and 255 cm $^{-1}$  gradually shrinks to nothing in intensity following the addition of CsCl. Based on the proposed model, this manifests itself as a sign of the gradual substitution of  $(Ga_2S_{6/2})$  by two  $(GaS_{3/2}Cl)$  units. When the CsCl/ $Ga_2S_3$  ratio is equal to two, complete substitution occurs. At the same time, the stoichiometric coordination of Ge is satisfied naturally. So the shoulder at 250 cm $^{-1}$  also vanishes.

Secondly, the peak centered at about  $480 \text{ cm}^{-1}$  that can be ascribed to the vibration of S8 rings and/or multi-sulfur bonds comes out on the spectrum of Sample 6. Certainly, this is an important proof that the  $(GaS_{4-x}Cl_x)$  m.u. for x > 1 are formed because of the larger affinity of Ga–Cl atoms compared to Ga–S ones when more CsCl is added.

Thirdly, in the region  $290{\text -}360 \, \text{cm}^{-1}$ , a gradual spreading toward the lower wavenumber occurs from sample 1 to 4 (the content of CsCl is less than 20%) and no distinct extending toward high wavenumber can be observed. However, further adding CsCl, the broadband in this region splits into a shoulder at about  $340 \, \text{cm}^{-1}$  and a peak centered at about  $320 \, \text{cm}^{-1}$  that quickly strengthens in intensity. When less CsCl is introduced, the formed (GaS<sub>4-x</sub>Cl<sub>x</sub>)

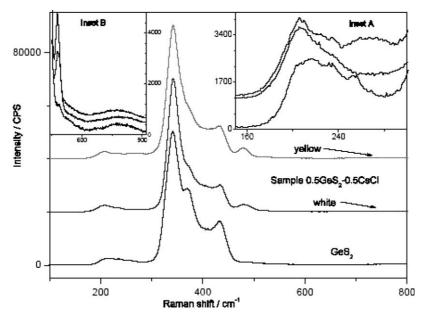


Fig. 5. Raman spectra of samples  $0.5 \text{GeS}_2$ –0.5 CsCl and  $\text{GeS}_2$  glass. The insert A and B are the spectra magnifying in *Y*-coordination within the region  $150-300 \text{ cm}^{-1}$  and  $440-920 \text{ cm}^{-1}$ , respectively. The sample  $0.5 \text{GeS}_2$ –0.5 CsCl is distinctly two phase separation to the eye.

tetrahedra, separated by the  $(GeS_4)$  tetrahedra, have less neighbor chance. So less  $(Ga_2S_{6-x}Cl_x)$  bridged units can be formed. Because of the slight overweight for Ge compared to Ga, the  $\nu_1$  mode of  $(GaS_4)$  should have an appreciably larger Raman shift than the corresponding one of  $(GeS_4)$ . Furthermore, the  $\nu_1$  mode of  $(GaS_{4-x}Cl_x)$  and  $(GaS_4)$  should have the same Raman shift due to the similarity of S and Cl. On the other hand, considering the effect of  $Cs^+$  according to the proposed model, the  $\nu_1$  mode of  $(GaS_{4-x}Cl_x)$  within the glasses should shift toward the lower wavenumber compared to the sole  $(GaS_{4-x}Cl_x)$  units. Combining the above two aspects, the  $\nu_1$  mode of  $(GaS_{4-x}Cl_x)$  within the

glasses probably has a less shift toward the lower wavenumber. So this successfully elucidates the slight shift of the broadband within this region when the amount of CsCl is less than 20%. Further increasing the content of CsCl, the chance for two  $(GaS_{4-x}Cl_x)$  units meeting is enhanced. Important proof can be acquired from the evolution of the peak located at about  $320 \text{ cm}^{-1}$  that is a characteristic peak of  $(Ga_2S_{6-x}Cl_x)$  bridged units.

Finally, the evolution of the shoulder within the region 400–460 cm<sup>-1</sup> also verifies this. When the amount of CsCl is less than 20%, almost no change occurs within this region. But when the amount of CsCl is more than 20%, this

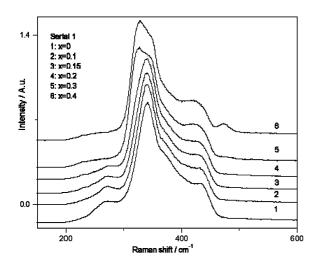


Fig. 6. Raman spectra of samples on serial 1 within  $GeS_2$ – $Ga_2S_3$ –CsCl system.

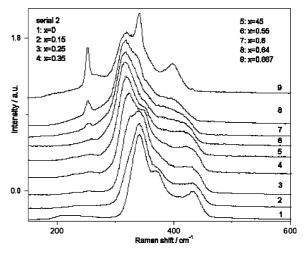


Fig. 7. Raman spectra of glasses on serial 2 within  $GeS_2$ – $Ga_2S_3$ –CsCl system.

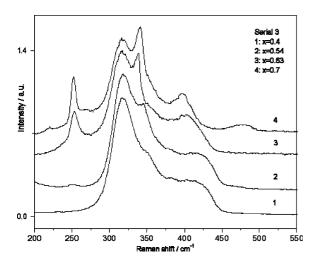


Fig. 8. Raman spectra of samples on serial 3 within GeS<sub>2</sub>–Ga<sub>2</sub>S<sub>3</sub>–CsCl system.

shoulder quickly strengthens in intensity and shifts toward the lower wavenumber. This just can be ascribed to the contribution of the  $\nu_1$  mode of  $(Ga_2S_{6-x}Cl_x)$  bridged units.

Fig. 7 presents the Raman spectra of samples on serial 2. It clearly reveals the evolution of spectra from a 3-dimentional network of GeS<sub>2</sub> glass to 1-dimentional chains of the Ga<sub>2</sub>S<sub>3</sub>–2CsCl glass. Spectral evolutional tendency of samples on serial 1 is exhibited more distinctly. Simultaneously, the evolutional course of the peak sited at about  $268 \, \mathrm{cm}^{-1}$  that is ascribed to the mode of  $v_3^{(\mathrm{Ag})} + v_4^{(\mathrm{Ag})}$  of  $(\mathrm{Ga}_2\mathrm{S}_4\mathrm{Cl}_2)$  bridged units also provides another important proof for the proposed micro-structural model.

The characteristic of samples on serial 3 is that the ratio of  $Ga_2S_3$  and CsCl remains constant at 3:7. A similar evolution as seen on serial 2 can be found on this serial (Fig. 8). In addition, more Raman spectral characteristics of  $(Ga_2Cl_6)$  bridged units come out on the location at 221 and  $468 \text{ cm}^{-1}$ . Finally, the characteristic peak of  $S_8$  rings is not presented on the spectra of samples 1–3. This suggests that multi-sulfur bonds are formed firstly following the substitutions of Ga–S bonds by Ga–Cl bonds.  $S_8$  rings appear only after enough multi-sulfur bonds are formed.

#### 4. Conclusions

Through considering the effect of  $Cs^+$  ions on  $(GaS_{4-x}Cl_x)$  mixed tetrahedral and  $(Ga_2S_{6-x}Cl_x)$  bridged units, similarities and variances of Raman spectra between the  $Ga_2S_3$ –2CsCl glass and  $GaCl_3$  molecule are ascribed reasonably and the Raman spectral evolution of samples within  $GeS_2$ – $Ga_2S_3$ –CsCl glassy system is elucidated successfully. At the same time, the following conclusions can be deduced:

- 1. The added Cs<sup>+</sup> ions are coordinated as the form of Cl ions for the nearest neighbor.
- 2. When the amount of CsCl is less than 20%, the  $(GaS_{4-x}Cl_x)$  mixed tetrahedra are homogeneously dispersed in the glassy net mainly in the apex-sharing form through the two-coordination sulfur. Originating from the addition of CsCl, the  $\nu_1$  mode of  $(GaS_{4-x}Cl_x)$  shifts towards a lower wave number.
- Following the further addition of CsCl, when the content of CsCl is more than 20%, the bridged units (Ga<sub>2</sub>S<sub>6-x</sub> Cl<sub>x</sub>) are formed easily within the GeS<sub>2</sub>-Ga<sub>2</sub>S<sub>3</sub>-CsCl glassy net.

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